

Transistors

# 2.5V Drive Nch+Nch MOS FET

## QS6K1

●Structure

Silicon N-channel  
 MOS FET

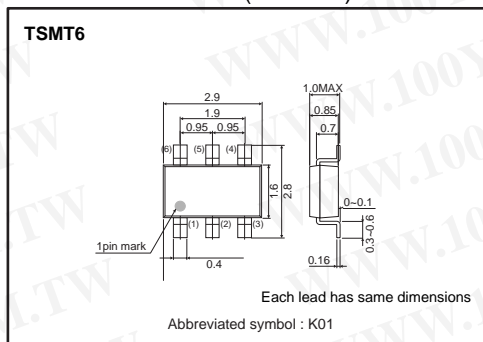
●Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (TSMT6).

●Application

Power switching, DC / DC converter.

●External dimensions (Unit : mm)



●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
QS6K1		○

●Absolute maximum ratings (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2>

Parameter	Symbol	Limits	Unit	
Drain-source voltage	$V_{DS}$	30	V	
Gate-source voltage	$V_{GS}$	12	V	
Drain current	Continuous	$I_D$	$\pm 1.0$	A
	Pulsed	$I_{DP}$ *1	$\pm 4.0$	A
Source current (Body diode)	Continuous	$I_S$	0.8	A
	Pulsed	$I_{SP}$ *1	4.0	A
Total power dissipation (Tc=25°C)	$P_D$ *2	1.25	W / TOTAL	
		0.9	W / ELEMENT	
Channel temperature	$T_{ch}$	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	

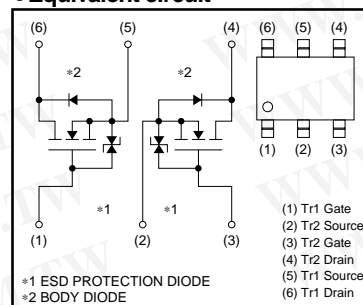
\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$   
 \*2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$ *	100	°C / W / TOTAL
		139	°C / W / ELEMENT

\* Mounted on a ceramic board

●Equivalent circuit



\*1 A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

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### ●Electrical characteristics (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	–	–	10	μA	V <sub>GS</sub> =12V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	30	–	–	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	–	–	1	μA	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	0.5	–	1.5	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	R <sub>DS(on)</sub> *	–	170	238	mΩ	I <sub>D</sub> =1.0A, V <sub>GS</sub> =4.5V
		–	180	252		I <sub>D</sub> =1.0A, V <sub>GS</sub> =4.0V
		–	260	364		I <sub>D</sub> =1.0A, V <sub>GS</sub> =2.5V
Forward transfer admittance	Y <sub>fs</sub>  *	1.0	–	–	S	I <sub>D</sub> =1.0A, V <sub>DS</sub> =10V
Input capacitance	C <sub>iss</sub>	–	77	–	pF	V <sub>DS</sub> =10V
Output capacitance	C <sub>oss</sub>	–	25	–	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	–	15	–	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	–	7	–	ns	I <sub>D</sub> =500mA, V <sub>DD</sub> ≐15V
Rise time	t <sub>r</sub> *	–	7	–	ns	V <sub>GS</sub> =4.5V
Turn-off delay time	t <sub>d(off)</sub> *	–	15	–	ns	R <sub>L</sub> =30.0Ω
Fall time	t <sub>f</sub> *	–	6	–	ns	R <sub>G</sub> =10Ω
Total gate charge	Q <sub>g</sub> *	–	1.7	2.4	nC	V <sub>DD</sub> ≐15V
Gate-source charge	Q <sub>gs</sub> *	–	0.4	–	nC	V <sub>GS</sub> =4.5V
Gate-drain charge	Q <sub>gd</sub> *	–	0.4	–	nC	I <sub>D</sub> =1.0A

\*Pulsed

### ●Body diode characteristics (Source-Drain) (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V <sub>SD</sub> *	–	–	1.2	V	I <sub>S</sub> =3.2A, V <sub>GS</sub> =0V

\*Pulsed

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●Electrical characteristic curves

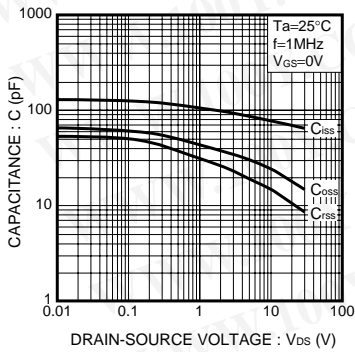


Fig.1 Typical Capacitance vs. Drain-Source Voltage

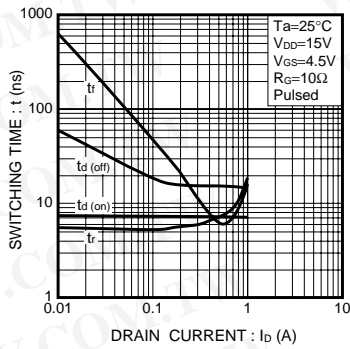


Fig.2 Switching Characteristics

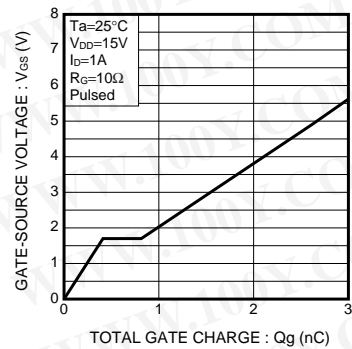


Fig.3 Dynamic Input Characteristics

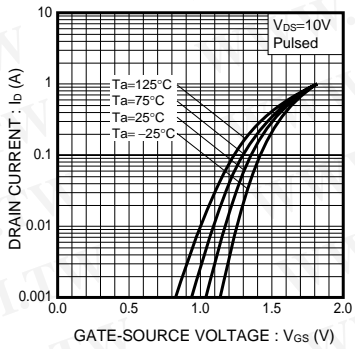


Fig.4 Typical Transfer Characteristics

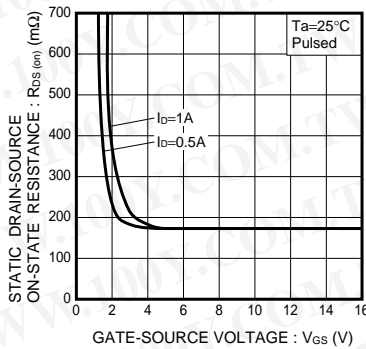


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

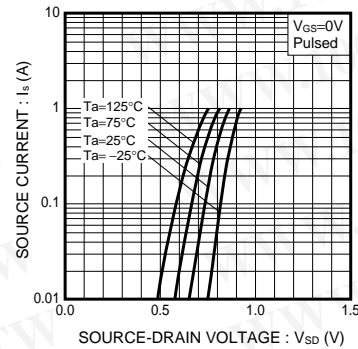


Fig.6 Source Current vs. Source-Drain Voltage

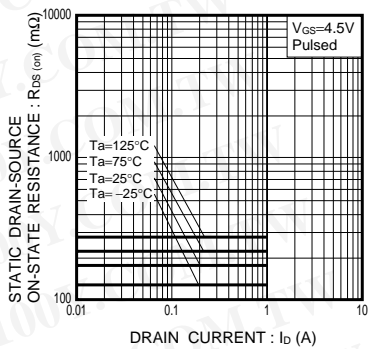


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (I)

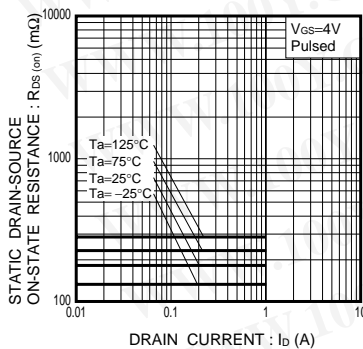


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current (II)

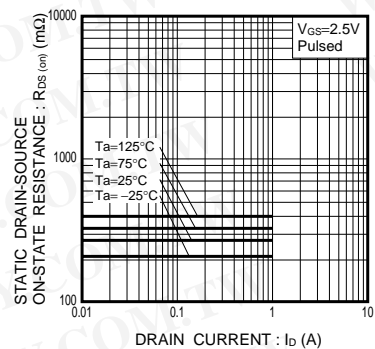


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current (III)

## Appendix

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